Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

- 1-56. (Cancelled)
- 57. (Previously Presented) A plurality of carbon nanosheets on a substrate, each of the plurality of carbon nanosheets having a thickness of 2 nanometers or less, wherein the plurality of carbon nanosheets are aligned and stand on their edges roughly vertically to the substrate.
 - 58. (Previously Presented) The plurality of carbon nanosheets of claim 57, wherein: the thickness is 1 nanometer or less; and each of the plurality of carbon nanosheets comprises one to three graphene layers.
- 59. (Previously Presented) The plurality of carbon nanosheets of claim 58, wherein each of the plurality of carbon nanosheets comprises a single graphene layer.
- 60. (Previously Presented) The plurality of carbon nanosheets of claim 57, wherein: the specific surface area of the each of the plurality of carbon nanosheets is between $1000 \text{ m}^2/\text{g}$ to $2600 \text{ m}^2/\text{g}$;

each of the plurality of carbon nanosheets has a height between 100 nm and 8 μ m; and

the plurality of carbon nanosheets are in substantially pure form.

- 61. (Cancelled)
- 62. (Previously Presented) A composition comprising a plurality of carbon nanoflakes having a specific surface area between $1000 \text{ m}^2/\text{g}$ and $2600 \text{ m}^2/\text{g}$, wherein the carbon nanoflakes are aligned, freestanding and stand on their edges roughly vertically to a substrate.
- 63. (Previously Presented) The composition of claim 62, wherein each of the plurality of carbon nanoflakes has a thickness of 10 nanometers or less.

64. (Previously Presented) The composition of claim 63, wherein:

each of the plurality of carbon nanoflakes has a thickness of 2 nanometers or less; and

the specific surface area of the each of the plurality of carbon nanoflakes is between 2000 m^2/g and 2600 m^2/g .

- 65. (Withdrawn) A method of making carbon nanoflakes comprising forming the nanoflakes on a substrate using RF-PECVD, wherein the carbon nanoflakes are aligned, freestanding and stand on their edges roughly vertically to the substrate and have a specific surface area between $1000 \text{ m}^2/\text{g}$ and $2600 \text{ m}^2/\text{g}$.
- 66. (Withdrawn) The method of claim 65, wherein RF-PECVD is inductively or capacitively coupled.
- 67. (Withdrawn) The method of claim 65, further comprising:
 increasing the substrate temperature during nucleation phase of carbon nanoflake
 synthesis to form carbon nanosheets comprising a single graphene layer; and
 attaching a grounding electrode to the substrate during a nucleation phase of
 nanoflake formation on the substrate.
 - 68. (Withdrawn) The method of claim 65, wherein: the substrate temperature is between 550 °C and 950 °C; the PECVD chamber pressure is between 50 mTorr and 200 mTorr; and PECVD plasma power is equal to or greater than 700 W.
- 69. (Withdrawn) The method of claim 65, wherein the CVD source gas comprises methane or acetylene, such that the CVD source gas contains a methane to hydrogen ratio between 0.05:99.95 and 100:0, or an acetylene to hydrogen ratio between 0.05:99.95 and 60:40.
- 70. (Withdrawn) A method of making carbon nanosheets, comprising:
 forming the nanosheets on a substrate, wherein the carbon nanosheets are aligned and stand on their edges roughly vertically to the substrate; and

increasing the substrate temperature during a nucleation phase of carbon nanosheet formation.

- 71. (Withdrawn) The method of claim 70, wherein inductively or capacitively coupled RF-PECVD is used to form the nanosheets.
- 72. (Withdrawn) The method of claim 70, further comprising attaching a grounding electrode to the substrate during a nucleation phase of nanoflake formation on the substrate.
 - 73. (Withdrawn) The method of claim 70, wherein: the substrate temperature is between 550 °C and 950 °C; the PECVD chamber pressure is between 50 mTorr and 200 mTorr; and PECVD plasma power is equal to or greater than 700 W.
- 74. (Withdrawn) The method of claim 70, wherein the CVD source gas comprises methane or acetylene, such that the CVD source gas contains a methane to hydrogen ratio between 0.05:99.95 and 100:0, or an acetylene to hydrogen ratio between 0.05:99.95 and 60:40.
- 75. (Previously Presented) An article comprising the plurality of carbon nanosheets of claim 57, wherein the article is selected from a group consisting of a field emitter, a catalyst support, a hydrogen storage device, a sensor, a blackbody absorber, a composite material, and a coating.
- 76. (Previously Presented) An article comprising the plurality of carbon nanosheets of claim 62, wherein the article is selected from a group consisting of a field emitter, a catalyst support, a hydrogen storage device, a sensor, a blackbody absorber, a composite material, and a coating.

77-78. (Cancelled)

- 79. (Previously Presented) The plurality of carbon nanosheets of claim 57, wherein the carbon nanosheets comprise crystalline carbon nanosheets.
- 80. (Previously Presented) The plurality of carbon nanosheets of claim 62, wherein the carbon nanosheets comprise crystalline carbon nanosheets.